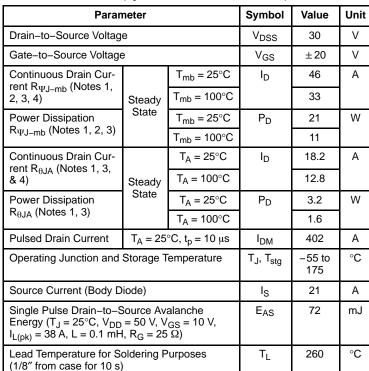
Power MOSFET 30 V, 4.7 mΩ, 46 A, Single N–Channel

Features

- Small Footprint (3.3 x 3.3 mm) for Compact Design
- Low R_{DS(on)} to Minimize Conduction Losses
- Low Capacitance to Minimize Driver Losses
- NVTFS4824NWF Wettable Flanks Product
- AEC–Q101 Qualified and PPAP Capable
- These Devices are Pb–Free, Halogen Free/BFR Free and are RoHS Compliant



Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

THERMAL RESISTANCE MAXIMUM RATINGS (Note 1)

Parameter	Symbol	Value	Unit
Junction-to-Mounting Board (top) - Steady State (Notes 2 and 3)	$R_{\PsiJ-mb}$	7.2	°C/W
Junction-to-Ambient - Steady State (Note 3)	R_{\thetaJA}	47	

1. The entire application environment impacts the thermal resistance values shown, they are not constants and are only valid for the particular conditions noted.

2. Psi (Ψ) is used as required per JESD51–12 for packages in which substantially less than 100% of the heat flows to single case surface.

Surface-mounted on FR4 board using a 650 mm², 2 oz. Cu pad.
Maximum current for pulses as long as 1 second is higher but is dependent

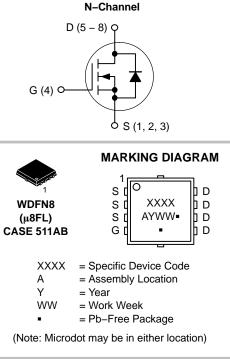
on pulse duration and duty cycle.



ON Semiconductor®

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V _{(BR)DSS}	R _{DS(on)} MAX	I _D MAX
30 V	4.7 mΩ @ 10 V	46 A
30 V	7.5 mΩ @ 4.5 V	40 A



ORDERING INFORMATION

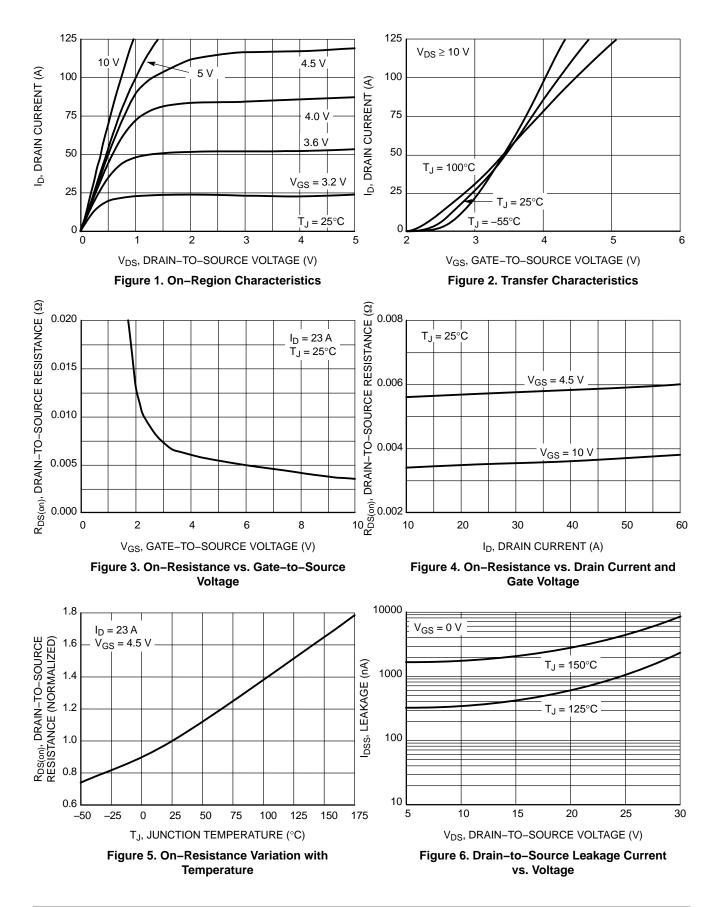
See detailed ordering, marking and shipping information in the package dimensions section on page 5 of this data sheet.

ELECTRICAL CHARACTERISTICS ($T_J = 25^{\circ}C$ unless otherwise noted)

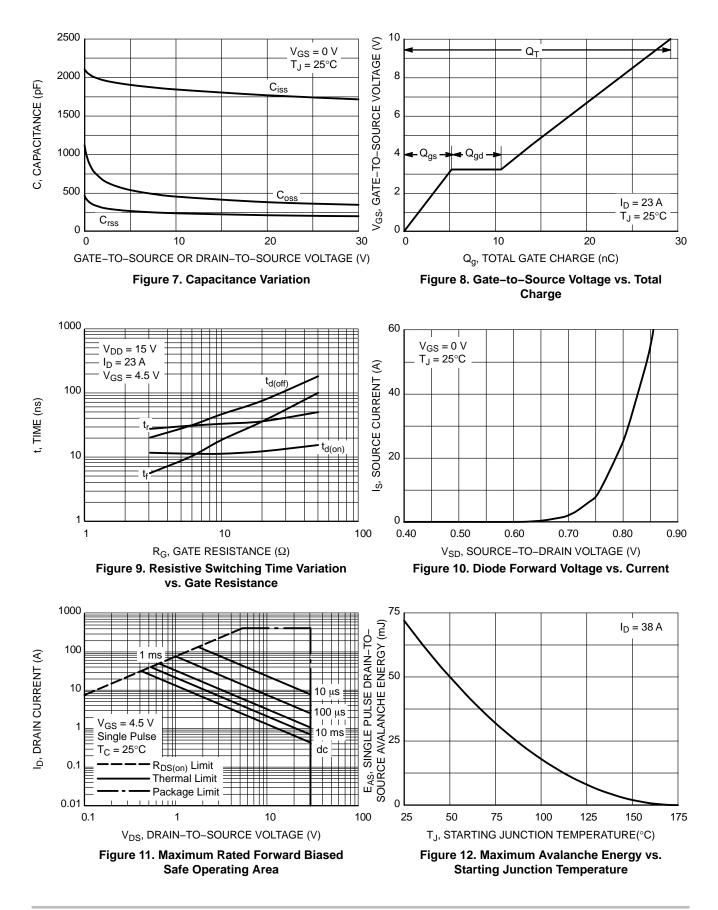
Parameter	Symbol	Test Condition		Min	Тур	Мах	Unit
OFF CHARACTERISTICS		•					
Drain-to-Source Breakdown Voltage	V _{(BR)DSS}	V_{GS} = 0 V, I _D = 250 μ A		30			V
Zero Gate Voltage Drain Current	I _{DSS}	V _{GS} = 0 V, V _{DS} = 30 V	$T_J = 25^{\circ}C$			1.0	μΑ
			T _J = 125°C			10	
Gate-to-Source Leakage Current	I _{GSS}	$V_{DS} = 0 \text{ V}, V_{GS} = \pm 20 \text{ V}$				±100	nA
ON CHARACTERISTICS (Note 5)							
Gate Threshold Voltage	V _{GS(TH)}	$V_{GS} = V_{DS}, I_{D}$	a = 250 μA	1.5		2.5	V
Drain-to-Source On Resistance	R _{DS(on)}	V _{GS} = 10 V, I _D = 23 A			3.5	4.7	mΩ
		V _{GS} = 4.5 V, I _D = 23 A			5.7	7.5	
Forward Transconductance	9 _{FS}	V _{DS} = 1.5 V,	I _D = 20 A		56		S
CHARGES AND CAPACITANCES							
Input Capacitance	C _{iss}	V _{GS} = 0 V, f = 1.0 MHz, V _{DS} = 12 V			1740		pF
Output Capacitance	C _{oss}				360		1
Reverse Transfer Capacitance	C _{rss}	1		200		1	
Total Gate Charge	Q _{G(TOT)}	$V_{GS} = 4.5 \text{ V}, V_{DS} = 15 \text{ V}, I_D = 23 \text{ A}$ $V_{GS} = 10 \text{ V}, V_{DS} = 15 \text{ V}, I_D = 23 \text{ A}$			14		nC
Threshold Gate Charge	Q _{G(TH)}				1.6		
Gate-to-Source Charge	Q_{GS}				5.3		
Gate-to-Drain Charge	Q _{GD}				5.5		
Total Gate Charge	Q _{G(TOT)}				29		nC
SWITCHING CHARACTERISTICS (No	te 6)						
Turn-On Delay Time	t _{d(on)}				12		ns
Rise Time	t _r	V _{GS} = 4.5 V, V	_{DS} = 15 V,		27		
Turn-Off Delay Time	t _{d(off)}	V_{GS} = 4.5 V, V_{DS} = 15 V, I _D = 15 A, R _G = 3.0 Ω			20		
Fall Time	t _f				6		
DRAIN-SOURCE DIODE CHARACTER	ISTICS						
Forward Diode Voltage	V _{SD}	$V_{GS} = 0 V,$	$T_J = 25^{\circ}C$		0.81	1.1	V
	$I_S = 23 \text{ A}$ $T_J = 125^{\circ}\text{C}$	0.69		1			
Reverse Recovery Time	t _{RR}	$V_{GS} = 0 V,$ $dI_{S}/dt = 100 A/\mu s,$ $I_{S} = 23 A$			19		ns
Charge Time	t _a				9.1		1
Discharge Time	t _b				9.6		1
Reverse Recovery Charge	Q _{RR}				8.8		nC

5. Pulse Test: Pulse Width ≤ 300 μs, Duty Cycle ≤ 2%.
6. Switching characteristics are independent of operating junction temperatures.

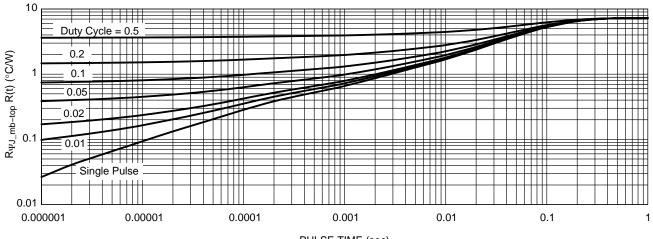
TYPICAL CHARACTERISTICS



TYPICAL CHARACTERISTICS



TYPICAL CHARACTERISTICS



PULSE TIME (sec) Figure 13. Thermal Response

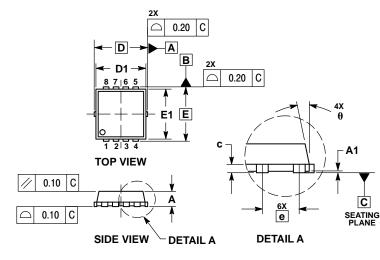
DEVICE ORDERING INFORMATION

Device	Marking	Package	Shipping [†]		
NVTFS4824NTAG	4824	WDFN8 (Pb-Free)	1500 / Tape & Reel		
NVTFS4824NWFTAG	24WF	WDFN8 (Pb-Free)	1500 / Tape & Reel		
NVTFS4824NTWG	4824	WDFN8 (Pb-Free)	5000 / Tape & Reel		
NVTFS4824NWFTWG	24WF	WDFN8 (Pb–Free)	5000 / Tape & Reel		

+For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

PACKAGE DIMENSIONS

WDFN8 3.3x3.3, 0.65P CASE 511AB ISSUE D



8X k 0.10 С A В ŧ 0.05 С e/2 4X E2 F3 м V D2 G-**BOTTOM VIEW**

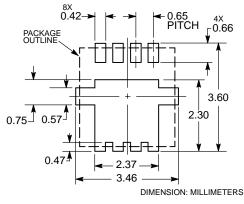
NOTES:

DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994.
CONTROLLING DIMENSION: MILLIMETERS.

DIMENSION D1 AND E1 DO NOT INCLUDE MOLD FLASH PROTRUSIONS OR GATE BURRS. 3.

	MILLIMETERS INCHES						
DIM	MIN	NOM	MAX	MIN	NOM	MAX	
Α	0.70	0.75	0.80	0.028	0.030	0.031	
A1	0.00		0.05	0.000		0.002	
p	0.23	0.30	0.40	0.009	0.012	0.016	
С	0.15	0.20	0.25	0.006	0.008	0.010	
D	3.30 BSC			0.130 BSC			
D1	2.95	3.05	3.15	0.116	0.120	0.124	
D2	1.98	2.11	2.24	0.078	0.083	0.088	
E	3.30 BSC			0.130 BSC			
E1	2.95	3.05	3.15	0.116	0.120	0.124	
E2	1.47	1.60	1.73	0.058	0.063	0.068	
E3	0.23	0.30	0.40	0.009	0.012	0.016	
е		0.65 BSC			0.026 BSC		
G	0.30	0.41	0.51	0.012	0.016	0.020	
к	0.65	0.80	0.95	0.026	0.032	0.037	
L	0.30	0.43	0.56	0.012	0.017	0.022	
L1	0.06	0.13	0.20	0.002	0.005	0.008	
м	1.40	1.50	1.60	0.055	0.059	0.063	
θ	0 °		12 °	0 °		12 °	

SOLDERING FOOTPRINT*



*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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